

# **RL201 - RL207** AXIAL LEADED SILICON RECTIFIER DIODES

## VOLTAGE RANGE: 50 - 1000V

### CURRENT: 2.0 A

#### Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

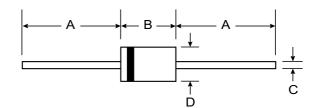
#### Mechanical Data

- Case: DO-15
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.40 grams (approx.)
- Mounting Position: Any
- Marking: Type Number

1. . 16







DO 45									
DU-15									
Min	Max								
25.40	—								
5.50	7.62								
0.686	0.889								
2.60	3.60								
All Dimensions in mm									
	25.40 5.50 0.686 2.60								

### Maximum Ratings and Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	RL201	RL202	RL203	RL204	RL205	RL206	RL207	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) $@T_A = 75^{\circ}C$	lo	2.0					А		
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	Ігѕм	70						A	
Forward Voltage @I <sub>F</sub> = 2.0A	Vfm	1.0					V		
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	Iгм	5.0 50						μA	
Typical Junction Capacitance (Note 2)	Cj	20					pF		
Typical Thermal Resistance Junction to Ambient (Note 1)	RθJA	40					K/W		
Operating Temperature Range	Tj	-65 to +125					°C		
Storage Temperature Range	Тѕтс	-65 to +150					°C		

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.



